1. General description

PNP high-voltage low V_{CEsat} transistor in a SOT223 (SC-73) medium power Surface-Mounted Device (SMD) plastic package.

NPN complement: PBHV8115Z

2. Features and benefits

- · High voltage
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain h_{FE} at high I_C
- Medium power SMD plastic package

3. Applications

- · LED driver for LED chain module
- LCD backlighting
- · High Intensity Discharge (HID) front lighting
- · Hook switch for wired telecom
- Switch mode power supply

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-150	V
I _C	collector current		-	-	-1	Α
h _{FE}	DC current gain	V_{CE} = -10 V; I_{C} = -50 mA; T_{amb} = 25 °C	100	220	-	

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	C
2	С	collector		В
3	Е	emitter		- Tw
4	С	collector	∃1 ∃2 ∃3	Ė
			SC-73 (SOT223)	sym028



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6. Ordering information

Table 3. Ordering information

Type number Package						
	Name	Description	Version			
PBHV9115Z		plastic, surface-mounted package with increased heatsink; 4 leads; 2.3 mm pitch; 6.5 mm x 3.5 mm x 1.65 mm body	SOT223			

7. Marking

Table 4. Marking codes

Type number	Marking code
PBHV9115Z	V9115Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-200	V
V_{CEO}	collector-emitter voltage	open base		-	-150	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
I _C	collector current			-	-1	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-2	Α
I _{BM}	peak base current			-	-400	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.7	W
			[2]	-	1.4	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

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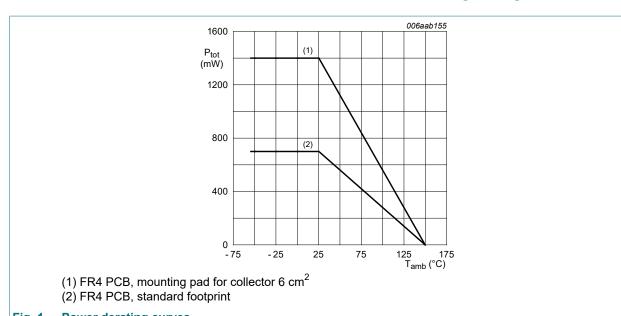


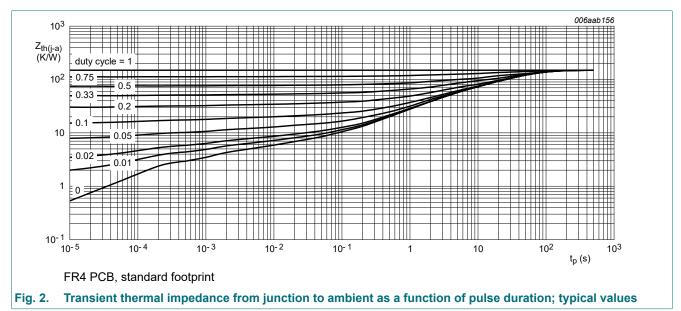
Fig. 1. Power derating curves

9. Thermal characteristics

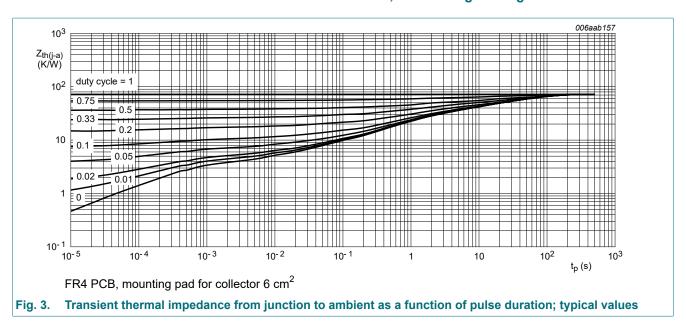
Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	-	175	K/W
junction to ambient		[2]	-	-	89	K/W	
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	20	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = -120 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CB} = -120 V; I _E = 0 A; T _j = 150 °C	-	-	-10	μA
I _{CES}	collector-emitter cut-off current	V _{CE} = -120 V; V _{BE} = 0 V; T _{amb} = 25 °C	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -4 \text{ V; } I_{C} = 0 \text{ A; } T_{amb} = 25 ^{\circ}\text{C}$	-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = -10 V; I _C = -50 mA; T _{amb} = 25 °C	100	220	-	
		V _{CE} = -10 V; I _C = -100 mA; T _{amb} = 25 °C	100	220	-	
		V_{CE} = -10 V; I_{C} = -1 A; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	10	30	-	
V _{CEsat}	collector-emitter	I _C = -100 mA; I _B = -10 mA; T _{amb} = 25 °C	-	-60	-120	mV
	saturation voltage	I _C = -100 mA; I _B = -20 mA; T _{amb} = 25 °C	-	-50	-100	mV
		I_{C} = 500 mA; I_{B} = -100 mA; T_{amb} = 25 °C	-	-150	-300	mV
V _{BEsat}	base-emitter saturation voltage	I_C = -1 A; I_B = -200 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-1.05	-1.2	V
t _d	delay time	$V_{CC} = -6 \text{ V}; I_C = -0.5 \text{ A}; I_{Bon} = -0.1 \text{ A};$	-	8	-	ns
t _r	rise time	I _{Boff} = 0.1 A; T _{amb} = 25 °C	-	282	-	ns
t _{on}	turn-on time		-	290	-	ns
t _s	storage time		-	430	-	ns
t _f	fall time		-	300	-	ns
t _{off}	turn-off time		-	730	-	ns
f _T	transition frequency	V_{CE} = -10 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	-	115	-	MHz
C _c	collector capacitance	V _{CB} = -20 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	10	-	pF
C _e	emitter capacitance	V_{EB} = -0.5 V; I_{C} = 0 A; I_{c} = 0 A; I_{c} = 0 A; I_{c} = 1 MHz; I_{amb} = 25 °C	-	150	-	pF

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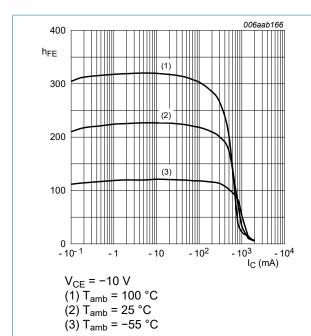


Fig. 4. DC current gain as a function of collector current; typical values

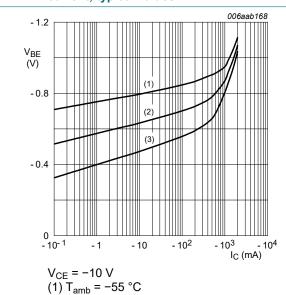


Fig. 6. Base-emitter voltage as a function of collector current; typical values

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) T_{amb} = 100 °C

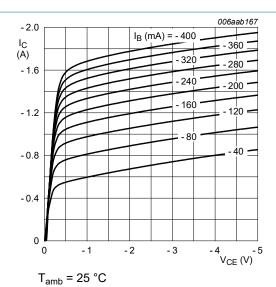
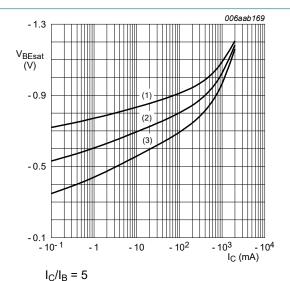


Fig. 5. Collector current as a function of collectoremitter voltage; typical values



 $(1) T_{amb} = -55 °C$ $(2) T_{amb} = 25 °C$

(3) $T_{amb} = 23^{\circ} C$

Fig. 7. Base-emitter saturation voltage as a function of collector current; typical values

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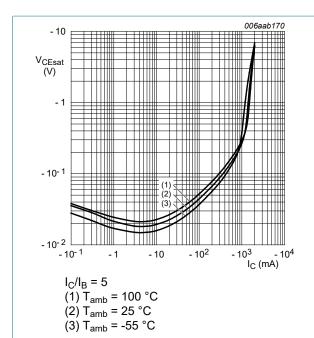


Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

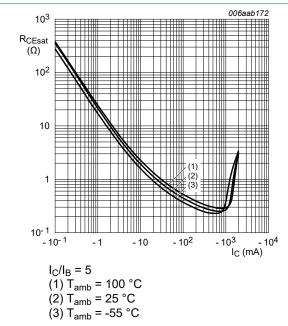


Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values

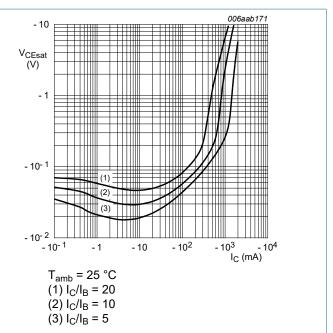


Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values

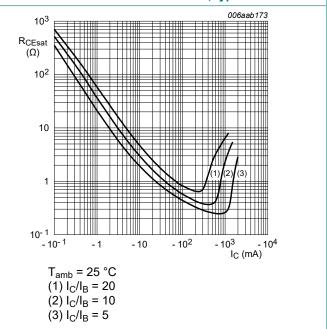
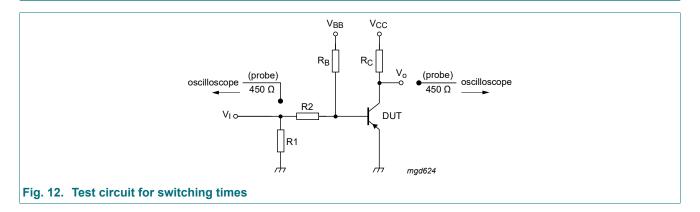


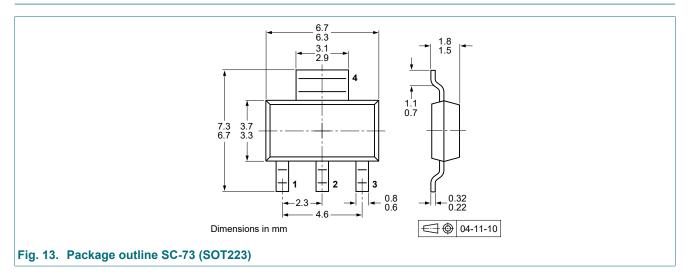
Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values

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11. Test information

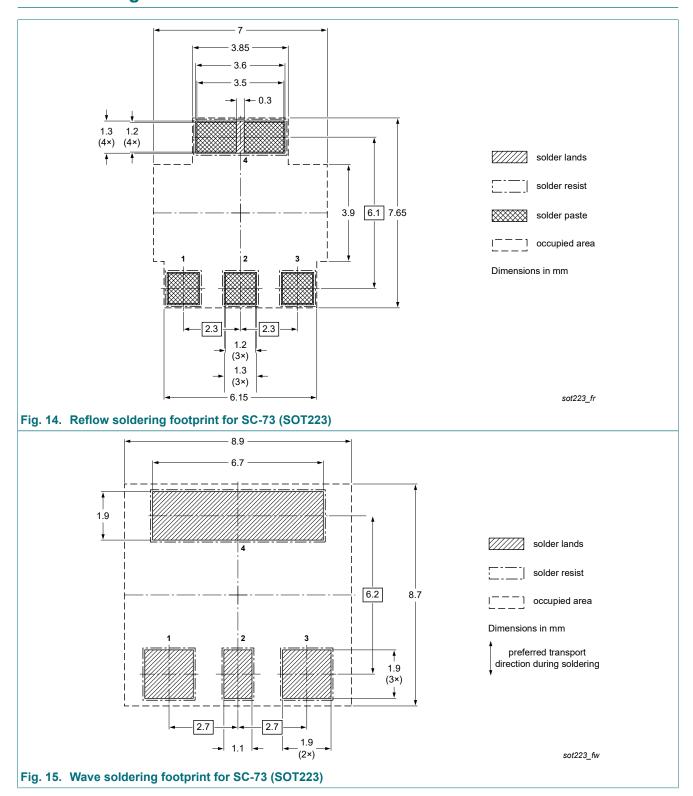


12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Table 6. Revision history								
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
PBHV9115Z v.4	20241008	Product data sheet	-	PBHV9115Z v.3				
Modifications:		 Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s). 						
PBHV9115Z v.3	20230717	Product data sheet	-	PBHV9115Z _2				
PBHV9115Z _2	20090109	Product data sheet	-	PBHV9115Z _1				
PBHV9115Z _1	20080214	Product data sheet	-	-				

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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